TOSHIBA

TOSHIBA Transistor

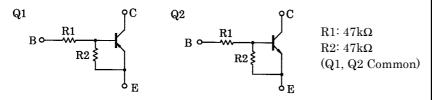
Silicon PNP Epitaxial Type (PCT Process) Silicon NPN Epitaxial Type (PCT Process)

RN4604

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

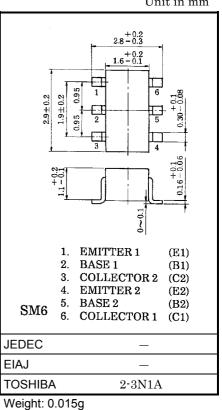
- Including two devices in SM6 (super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process

Equivalent Circuit and Bias Resister Values



Q1 Maximum Ratings (Ta = 25°C)

| Characteristic | Symbol | Rating | Unit |
|---------------------------|------------------|--------|------|
| Collector-base voltage | V _{CBO} | -50 | V |
| Collector-emitter voltage | V _{CEO} | -50 | V |
| Emitter-base voltage | V _{EBO} | -10 | V |
| Collector current | Ι _C | -100 | mA |



Q2 Maximum Ratings (Ta = 25°C)

| Characteristic | Symbol | Rating | Unit |
|---------------------------|------------------|--------|------|
| Collector-base voltage | V _{CBO} | 50 | V |
| Collector-emitter voltage | V _{CEO} | 50 | V |
| Emitter-base voltage | V _{EBO} | 10 | V |
| Collector current | Ι _C | 100 | mA |

000707EAA2

TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general
can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the
buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and
to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or
damage to property.

In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc...

The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.

Unit in mm

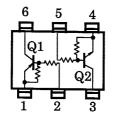
Q1, Q2 Common Maximum Ratings (Ta = 25°C)

| Characteristic | Symbol | Rating | Unit |
|-----------------------------|------------------|---------|------|
| Collector power dissipation | P _C * | 300 | mW |
| Junction temperature | Tj | 150 | °C |
| Storage temperature range | T _{stg} | -55~150 | °C |

* Total rating

Marking

Equivalent Circuit (Top View)



000707EAA2

 The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.

The information contained herein is subject to change without notice.

Q1 Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Circuit | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|-----------------------|-----------------|--|--------|------|-------|------|
| Collector cut-off current | I _{CBO} | _ | $V_{CB} = -50V, I_E = 0$ | _ | _ | -100 | nA |
| | ICEO | _ | $V_{CE} = -50V, I_B = 0$ | _ | _ | -500 | |
| Emitter cut-off current | I _{EBO} | _ | $V_{EB} = -10V, I_C = 0$ | -0.082 | _ | -0.15 | mA |
| DC current gain | h _{FE} | _ | $V_{CE} = -5V, I_C = -10mA$ | 80 | _ | — | — |
| Collector-emitter saturation voltage | V _{CE (sat)} | _ | I _C = −5mA, I _B = −0.25mA | _ | -0.1 | -0.3 | V |
| Input voltage (ON) | V _{I (ON)} | _ | $V_{CE} = -0.2V, I_{C} = -5mA$ | -1.5 | _ | -5.0 | V |
| Input voltage (OFF) | VI (OFF) | _ | $V_{CE} = -5V, I_C = -0.1mA$ | -1.0 | _ | -1.5 | V |
| Transition frequency | f _T | _ | V _{CE} = −10V, I _C = −5mA | _ | 200 | _ | MHz |
| Collector output capacitance | C _{ob} | _ | V _{CB} = -10V, I _E = 0, f = 1MHz | _ | 3 | 6 | pF |

Q2 Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Circuit | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|-----------------------|-----------------|--|-------|------|------|------|
| Collector cut-off current | I _{CBO} | - | V _{CB} = 50V, I _E = 0 | - | | 100 | nA |
| | ICEO | _ | V _{CE} = 50V, I _B = 0 | _ | _ | 500 | |
| Emitter cut-off current | I _{EBO} | _ | V _{EB} = 10V, I _C = 0 | 0.082 | _ | 0.15 | mA |
| DC current gain | h _{FE} | _ | V _{CE} = 5V, I _C = 10mA | 80 | _ | _ | — |
| Collector-emitter saturation voltage | V _{CE (sat)} | _ | I _C = 5mA, I _B = 0.25mA | _ | 0.1 | 0.3 | V |
| Input voltage (ON) | V _{I (ON)} | _ | V _{CE} = 0.2V, I _C = 5mA | 1.5 | _ | 5.0 | V |
| Input voltage (OFF) | V _{I (OFF)} | _ | V _{CE} = 5V, I _C = 0.1mA | 1.0 | _ | 1.5 | V |
| Transition frequency | f _T | — | V _{CE} = 10V, I _C = 5mA | _ | 250 | _ | MHz |
| Collector output capacitance | C _{ob} | — | V _{CB} = 10V, I _E = 0, f = 1 MHz | _ | 3 | 6 | pF |

Q1, Q2 Common Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Circuit | Test Condition | Min | Тур. | Max | Unit |
|----------------|--------|-----------------|----------------|------|------|------|------|
| Input resistor | R1 | _ | — | 32.9 | 47 | 61.1 | kΩ |
| Resistor ratio | R1/R2 | _ | — | 0.9 | 1.0 | 1.1 | _ |

TOSHIBA

